

and ground starts charging the 100 nF capacitor connected to it and generates supply voltage for the CMOS (MAXIM ICL715551PA) timer. The output voltage of the charge pump increases with increasing supply voltage. The charge pump maintains the voltage in the bootstrap capacitor, keeping the voltage above the undervoltage threshold level of the IR2125.

This improves system efficiency, expands voltage range, and reduces the cost of the power device required.

DESIGN CONSIDERATIONS

- The absolute maximum voltage supply voltage for the 555 is 18V, consider this when selecting the zener diode and its tolerance.
- The supply current at the V8 pin (I_{SS}) of the IR2125 increases with increasing temperature.
- The 100k 1 kW resistor should be sized according the maximum supply current at the high side of the IR2125, the minimum operating power supply voltage and the timing requirements.

CONCLUSION

This simple, inexpensive charge pump circuit overcomes the maximum on-time limitation of the bootstrap circuit. The circuit presented above utilizes the advantages of the bootstrap and charge pump technique providing excellent switching speed and steady state operation allowing the use of an N-channel MOS-gated power device as a high-side switch.

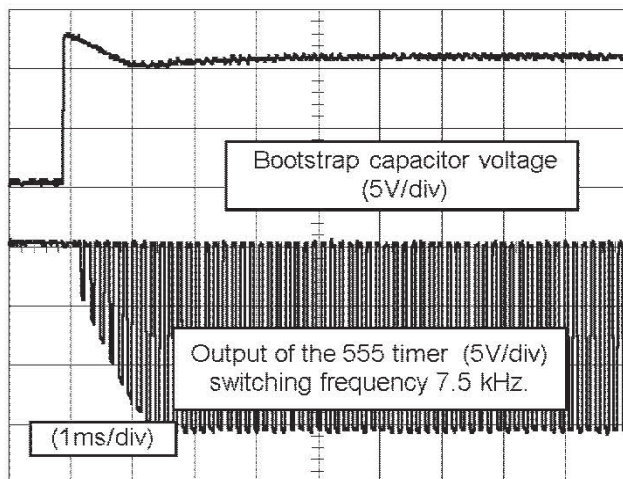


Figure 2